NSN 5961-01-371-3161

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-371-3161

Inclosure Material:
Metal and glass
Overall Length:
Between 0.150 inches and 0.192 inches

Terminal Length:
0.500 inches
Overall Diameter:
0.360 inches
Internal Configuration:
Junction contact
Mounting Method:

Features Provided:

Hermetically sealed case and electrostatic sensitive

Semiconductor Material:

Silicon

Terminal

Voltage Rating In Volts Per Characteristic:

50.0 reverse voltage, instantaneous

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pn; field force effort type: electrostatic charge

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

Olicii Lii

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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